

## Maximum Ratings

Maximum ratings are the extreme limits to which the MCU can be exposed without permanently damaging it.

The MCU contains circuitry to protect the inputs against damage from high static voltages; however, do not apply voltages higher than those shown in **Table 1**. Keep  $V_{IN}$  and  $V_{OUT}$  within the range  $V_{SS} \leq (V_{IN} \text{ or } V_{OUT}) \leq V_{DD}$ . Connect unused inputs to the appropriate voltage level, either  $V_{SS}$  or  $V_{DD}$ .

**Table 1. Maximum Ratings**

Rating	Symbol	Value	Unit
Supply Voltage	$V_{DD}$	-0.3 to +7.0	V
Current Drain per Pin (Excluding $V_{DD}$ and $V_{SS}$ )	I	25	mA
Input Voltage	$V_{IN}$	$V_{SS} - 0.3$ to $V_{DD} + 0.3$	V
EPROM Programming Voltage	$V_{PP}$	16.75	V
Storage Temperature Range	$T_{STG}$	-65 to +150	°C

**NOTE:** *This device is not guaranteed to operate properly at the maximum ratings. Refer to **5.0 V DC Electrical Characteristics** on page 135 and **3.3 V DC Electrical Characteristics** on page 136 for guaranteed operating conditions.*

## Operating Temperature Range

**Table 2. Operating Temperature Range**

Package Type	Symbol	Value	Unit
MC68HC705P9P <sup>(1)</sup> , DW <sup>(2)</sup> , S <sup>(3)</sup> (Standard) MC68HC705P9C <sup>(4)</sup> P, CDW, CS (Extended) MC68HC705P9V <sup>(5)</sup> P, VDW, VS (Automotive) MC68HC705P9M <sup>(6)</sup> P, MDW, MS (Automotive)	$T_A$	$T_L$ to $T_H$ 0 to 70 -40 to +85 -40 to +105 -40 to +125	°C

1. P = Plastic dual in-line package (PDIP)
2. DW = Small outline integrated circuit (SOIC)
3. S = Ceramic dual in-line package (Cerdip)
4. C = Extended temperature range (-40 to +85 °C)
5. V = Automotive temperature range (-40 to +105 °C)
6. M = Automotive temperature range (-40 to +125 °C)

## Thermal Characteristics

**Table 3. Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Thermal Resistance Plastic Dual In-Line Package (PDIP) Small Outline Integrated Circuit (SOIC) Ceramic Dual In-Line Package (Cerdip)	$\theta_{JA}$	60 60 60	°C/W

## Power Considerations

---

The average chip junction temperature,  $T_J$ , in °C can be obtained from:

$$T_J = T_A + (P_D \times \theta_{JA}) \quad (1)$$

where:

$T_A$  = ambient temperature in °C

$\theta_{JA}$  = package thermal resistance, junction to ambient in °C/W

$P_D = P_{INT} + P_{I/O}$

$P_{INT} = I_{CC} \times V_{CC}$  = chip internal power dissipation

$P_{I/O}$  = power dissipation on input and output pins (user-determined)

For most applications,  $P_{I/O} \ll P_{INT}$  and can be neglected.

Ignoring  $P_{I/O}$ , the relationship between  $P_D$  and  $T_J$  is approximately:

$$P_D = \frac{K}{T_J + 273 \text{ °C}} \quad (2)$$

Solving equations (1) and (2) for K gives:

$$K = P_D \times (T_A + 273 \text{ °C}) + \theta_{JA} \times (P_D)^2 \quad (3)$$

where K is a constant pertaining to the particular part. K can be determined from equation (3) by measuring  $P_D$  (at equilibrium) for a known  $T_A$ . Using this value of K, the values of  $P_D$  and  $T_J$  can be obtained by solving equations (1) and (2) iteratively for any value of  $T_A$ .

## 5.0 V DC Electrical Characteristics

**Table 4. DC Electrical Characteristics ( $V_{DD} = 5.0 \text{ Vdc}$ )<sup>(1)</sup>**

Characteristic	Symbol	Min	Typ <sup>(2)</sup>	Max	Unit
Output Voltage $I_{LOAD} = 10.0 \mu\text{A}$ $I_{LOAD} = -10.0 \mu\text{A}$	$V_{OL}$ $V_{OH}$	— $V_{DD} - 0.1$	— —	0.1 —	V
Output High Voltage ( $I_{LOAD} = -0.8 \text{ mA}$ ) PA7-PA0, PB7/SCK-PB5/SDO, PC7/ $V_{RH}$ -PC0, PD5, TCMP	$V_{OH}$	$V_{DD} - 0.8$	—	—	V
Output Low Voltage ( $I_{LOAD} = 1.6 \text{ mA}$ ) PA7-PA0, PB7/SCK-PB5/SDO, PC7/ $V_{RH}$ -PC0, PD5, TCMP	$V_{OL}$	—	—	0.4	V
Input High Voltage PA7-PA0, PB7/SCK-PB5/SDO, PC7/ $V_{RH}$ -PC0, PD5, PD7/TCAP, $\overline{\text{IRQ}}/V_{PP}$ , RESET, OSC1	$V_{IH}$	$0.7 \times V_{DD}$	—	$V_{DD}$	V
Input Low Voltage PA7-PA0, PB7/SCK-PB5/SDO, PC7/ $V_{RH}$ -PC0, PD5, PD7/TCAP, $\overline{\text{IRQ}}/V_{PP}$ , RESET, OSC1	$V_{IL}$	$V_{SS}$	—	$0.2 \times V_{DD}$	V
Supply Current <sup>(3) (4) (5) (6)</sup> Run Mode Wait Mode (ADC On) Wait Mode (ADC Off) Stop Mode 25 °C 0 to 70 °C (Standard) -40 to 125 °C	$I_{DD}$	— — — — — — —	4.7 2.1 1.3 2 — — —	6.5 2.9 1.9 30 50 100	mA mA mA $\mu\text{A}$ $\mu\text{A}$ $\mu\text{A}$
I/O Ports Hi-Z Leakage Current PA7-PA0, PB7/SCK-PB5/SDO, PC7/ $V_{RH}$ -PC0, PD5	$I_{IL}$	—	—	$\pm 10$	$\mu\text{A}$
ADC Ports Hi-Z Leakage Current	$I_{OZ}$	—	—	$\pm 1$	$\mu\text{A}$
Input Current RESET, $\overline{\text{IRQ}}/V_{PP}$ , OSC1, PD7/TCAP	$I_{IN}$	—	—	$\pm 1$	$\mu\text{A}$
Capacitance Ports (As Inputs or Outputs) RESET, $\overline{\text{IRQ}}/V_{PP}$	$C_{OUT}$ $C_{IN}$	— —	— —	12 8	pF
Programming Voltage	$V_{PP}$	16.25	16.5	16.75	V
Programming Current	$I_{PP}$	—	5	10	mA
Programming Time per Byte	$t_{EPGM}$	4	—	—	ms

1.  $V_{DD} = 5.0 \text{ Vdc} \pm 10\%$ ,  $V_{SS} = 0 \text{ Vdc}$ ,  $T_A = T_L$  to  $T_H$  unless otherwise noted
2. Typical values at midpoint of voltage range, 25 °C only
3. Run mode and wait mode  $I_{DD}$  measured using external square wave clock source ( $f_{OSC} = 4.2 \text{ MHz}$ ); all inputs 0.2 V from rail; no dc loads; less than 50 pF on all outputs;  $C_L = 20 \text{ pF}$  on OSC2
4. Wait mode and stop mode  $I_{DD}$  measured with all ports configured as inputs;  $V_{IL} = 0.2 \text{ V}$ ;  $V_{IH} = V_{DD} - 0.2 \text{ V}$
5. Stop mode  $I_{DD}$  measured with  $\text{OSC1} = V_{SS}$
6. Wait mode  $I_{DD}$  affected linearly by OSC2 capacitance

**3.3 V DC Electrical Characteristics**
**Table 5. DC Electrical Characteristics ( $V_{DD} = 3.3 \text{ Vdc}$ )<sup>(1)</sup>**

Characteristic	Symbol	Min	Typ <sup>(2)</sup>	Max	Unit	
Output Voltage ( $I_{LOAD} \leq 10.0 \mu\text{A}$ )	$V_{OL}$ $V_{OH}$	— $V_{DD} - 0.1$	— —	0.1 —	V	
Output High Voltage ( $I_{LOAD} = -0.2 \text{ mA}$ ) PA7-PA0, PB7/SCK-PB5/SDO, PC7/ $V_{RH}$ -PC0, PD5, TCMP	$V_{OH}$	$V_{DD} - 0.3$	—	—	V	
Output Low Voltage ( $I_{LOAD} = 0.4 \text{ mA}$ ) PA7-PA0, PB7/SCK-PB5/SDO, PC7/ $V_{RH}$ -PC0, PD5, TCMP	$V_{OL}$	—	—	0.3	V	
Input High Voltage PA7-PA0, PB7/SCK-PB5/SDO, PC7/ $V_{RH}$ -PC0, PD5, PD7/TCAP, $\overline{IRQ}/V_{PP}$ , RESET, OSC1	$V_{IH}$	$0.7 \times V_{DD}$	—	$V_{DD}$	V	
Input Low Voltage PA7-PA0, PB7/SCK-PB5/SDO, PC7/ $V_{RH}$ -PC0, PD5, PD7/TCAP, $\overline{IRQ}/V_{PP}$ , RESET, OSC1	$V_{IL}$	$V_{SS}$	—	$0.2 \times V_{DD}$	V	
Data-Retention Mode Supply Voltage	$V_{RM}$	2.0	—	—	V	
Supply Current <sup>(3) (4) (5) (6)</sup>						
Run Mode	$I_{DD}$	—	1.6	2.3	mA	
Wait Mode (ADC On)		—	0.9	1.3	mA	
Wait Mode (ADC Off)		—	0.4	0.6	mA	
Stop Mode		—	—	—	—	—
25 °C		—	1.0	20	$\mu\text{A}$	
0 to 70 °C (Standard)		—	—	40	$\mu\text{A}$	
-40 to 125 °C	—	—	—	50	$\mu\text{A}$	
I/O Ports Hi-Z Leakage Current PA7-PA0, PB7/SCK-PB5/SDO, PC7/ $V_{RH}$ -PC0, PD5	$I_{IL}$	—	—	$\pm 10$	$\mu\text{A}$	
Input Current RESET, $\overline{IRQ}/V_{PP}$ , OSC1, PD7/TCAP	$I_{IN}$	—	—	$\pm 1$	$\mu\text{A}$	
Capacitance						
Ports (As Inputs or Outputs)	$C_{OUT}$ $C_{IN}$	—	—	12	pF	
RESET, $\overline{IRQ}/V_{PP}$		—	—	8	pF	

1.  $V_{DD} = 3.3 \text{ Vdc} \pm 10\%$ ,  $V_{SS} = 0 \text{ Vdc}$ ,  $T_A = T_L$  to  $T_H$  unless otherwise noted

2. Typical values at midpoint of voltage range, 25 °C only

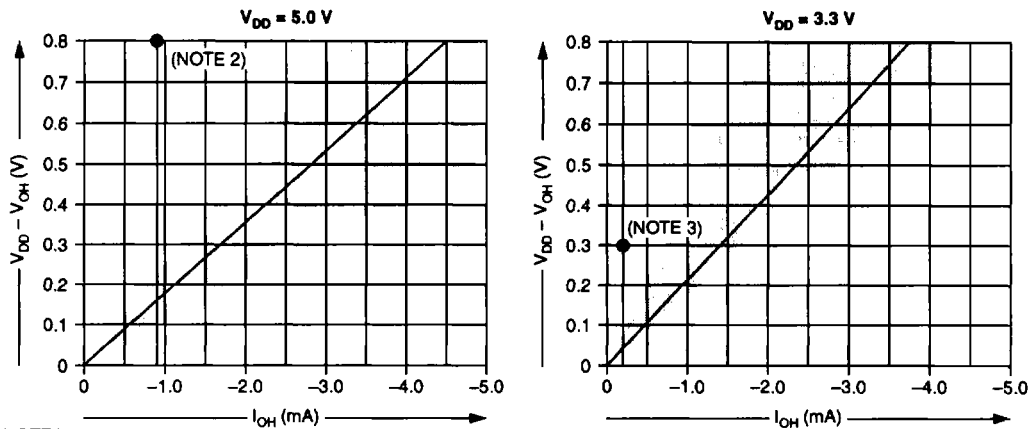
3. Run mode and wait mode  $I_{DD}$  measured using external square wave clock source ( $f_{OSC} = 2.1 \text{ MHz}$ ); all inputs 0.2 V from rail; no dc loads; less than 50 pF on all outputs;  $C_L = 20 \text{ pF}$  on OSC2

4. Wait mode and stop mode  $I_{DD}$  measured with all ports configured as inputs;  $V_{IL} = 0.2 \text{ V}$ ;  $V_{IH} = V_{DD} - 0.2 \text{ V}$

5. Stop mode  $I_{DD}$  measured with OSC1 =  $V_{SS}$

6. Wait mode  $I_{DD}$  affected linearly by OSC2 capacitance

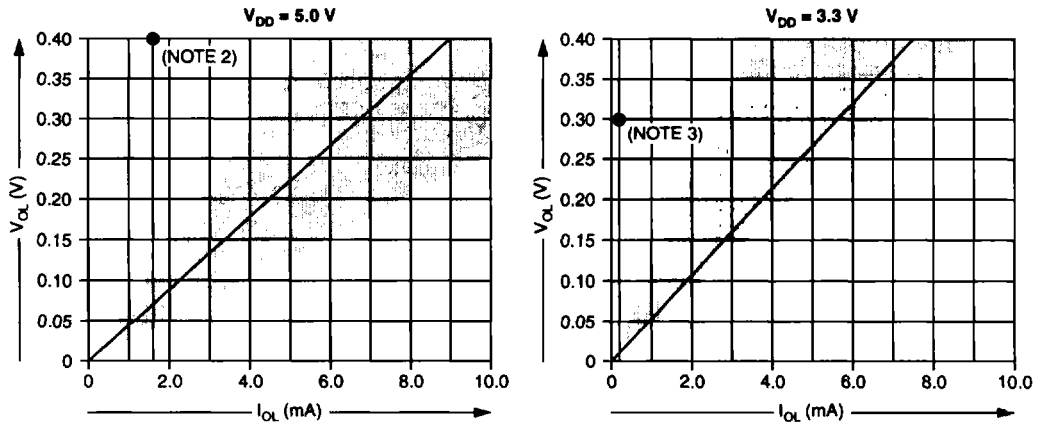
## Driver Characteristics



**NOTES:**

1. Shaded area indicates variation in driver characteristics due to changes in temperature and for normal processing tolerances. Within the limited range of values shown, V vs I curves are approximately straight lines.
2. At  $V_{DD} = 5.0$  V, devices are specified and tested for  $V_{OL} \leq 800$  mV @  $I_{OL} = -0.8$  mA.
3. At  $V_{DD} = 3.3$  V, devices are specified and tested for  $V_{OL} \leq 300$  mV @  $I_{OL} = -0.2$  mA.

**Figure 1. Typical High-Side Driver Characteristics**



**NOTES:**

1. Shaded area indicates variation in driver characteristics due to changes in temperature and for normal processing tolerances. Within the limited range of values shown, V vs I curves are approximately straight lines.
2. At  $V_{DD} = 5.0$  V, devices are specified and tested for  $V_{OL} \leq 400$  mV @  $I_{OL} = 1.6$  mA.
3. At  $V_{DD} = 3.3$  V, devices are specified and tested for  $V_{OL} \leq 300$  mV @  $I_{OL} = 0.4$  mA.

**Figure 2. Typical Low-Side Driver Characteristics**

## Typical Supply Current vs. Internal Clock Frequency

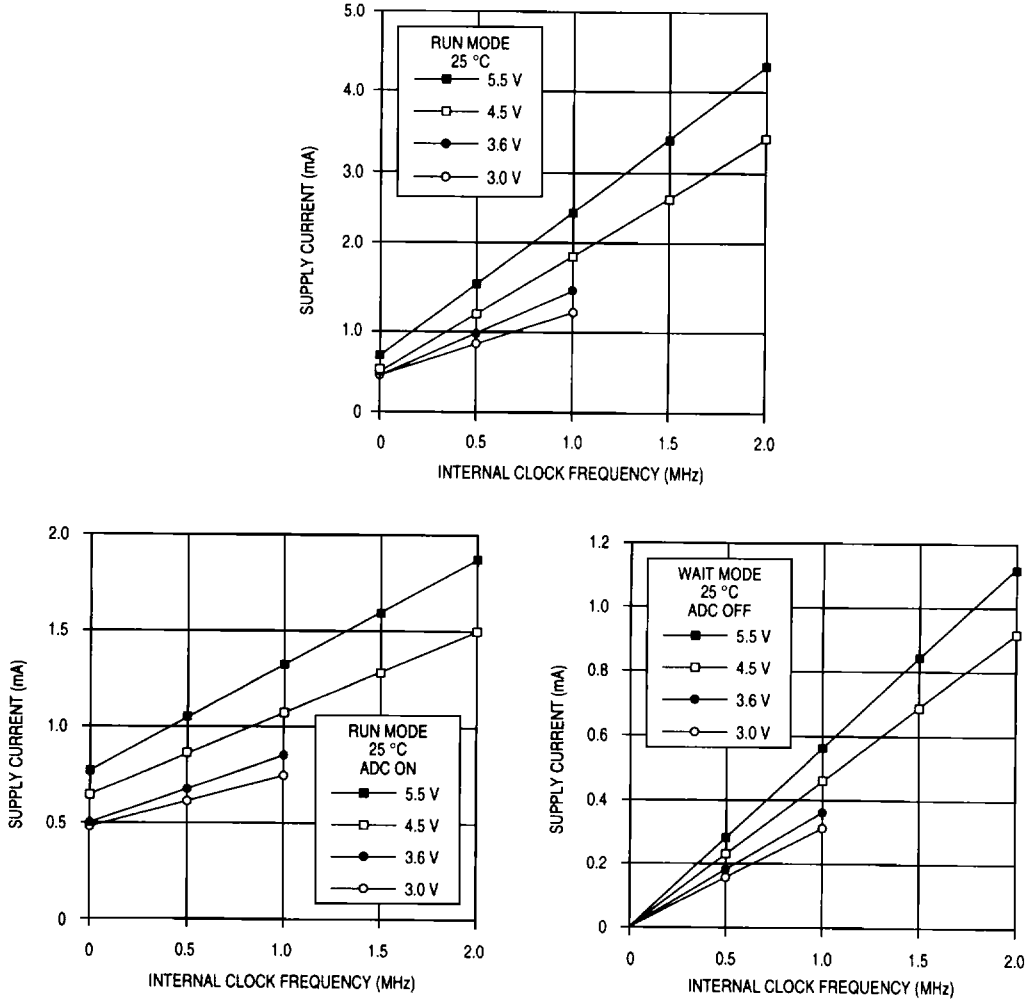


Figure 3. Typical Supply Current vs. Internal Clock Frequency

## Maximum Supply Current vs. Internal Clock Frequency

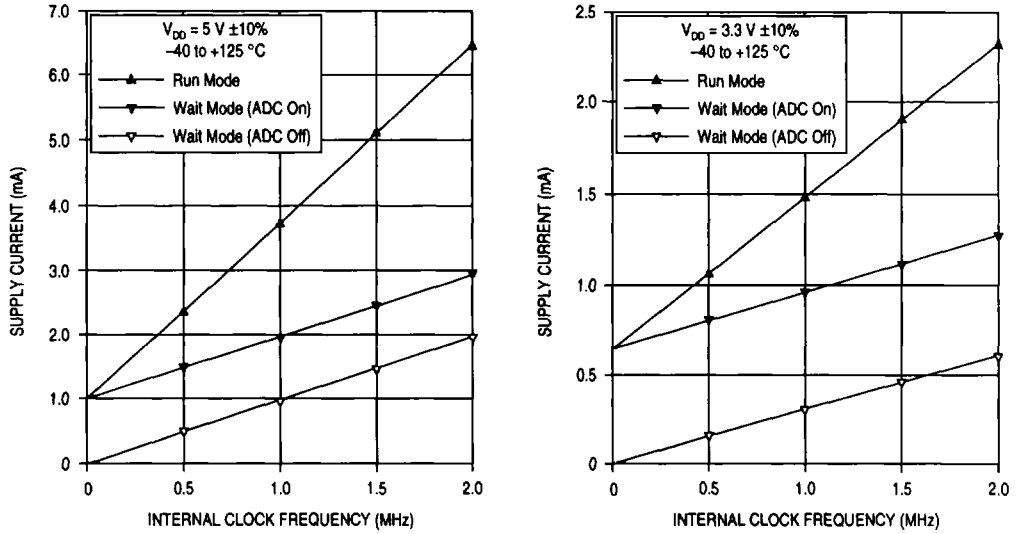


Figure 4. Maximum Supply Current vs. Internal Clock Frequency



## 5.0 V Control Timing

**Table 6. Control Timing ( $V_{DD} = 5.0 \text{ Vdc}$ )<sup>(1)</sup>**

Characteristic	Symbol	Min	Max	Unit
Oscillator Frequency Crystal External Clock	$f_{OSC}$	— dc	4.2 4.2	MHz
Internal Operating Frequency ( $f_{OSC} + 2$ ) Crystal External Clock	$f_{OP}$	— dc	2.1 2.1	MHz
Cycle Time ( $1 + f_{OP}$ )	$t_{CYC}$	480	—	ns
Crystal Oscillator Startup Time	$t_{OXOV}$	—	100	ms
Stop Recovery Startup Time (Crystal Oscillator)	$t_{LCH}$	—	100	ms
RESET Pulse Width	$t_{RL}$	1.5	—	$t_{CYC}$
Timer Resolution <sup>(2)</sup> Input Capture Pulse Width Input Capture Pulse Period	$t_{RESL}$ $t_H, t_L$ $t_{TLTL}$	4.0 125 Note <sup>(3)</sup>	— — —	$t_{CYC}$ ns $t_{CYC}$
Interrupt Pulse Width Low (Edge-Triggered)	$t_{LIH}$	125	—	ns
Interrupt Pulse Period	$t_{LIL}$	Note <sup>(4)</sup>	—	$t_{CYC}$
OSC1 Pulse Width	$t_{OH}, t_{OL}$	90	—	ns
RC Oscillator Stabilization Time	$t_{RCON}$	—	5	$\mu\text{s}$
ADC On Current Stabilization Time	$t_{ADON}$	—	100	$\mu\text{s}$

1.  $V_{DD} = 5.0 \text{ Vdc} \pm 10\%$ ,  $V_{SS} = 0 \text{ Vdc}$ ,  $T_A = T_L$  to  $T_H$  unless otherwise noted

2. A 2-bit prescaler in the timer is the limiting factor as it counts 4  $t_{CYC}$

3. The minimum  $t_{TLTL}$  should not be less than the number of interrupt service routine cycles plus 19  $t_{CYC}$

4. The minimum  $t_{LIL}$  should not be less than the number of interrupt service routine cycles plus 19  $t_{CYC}$

## 3.3 V Control Timing

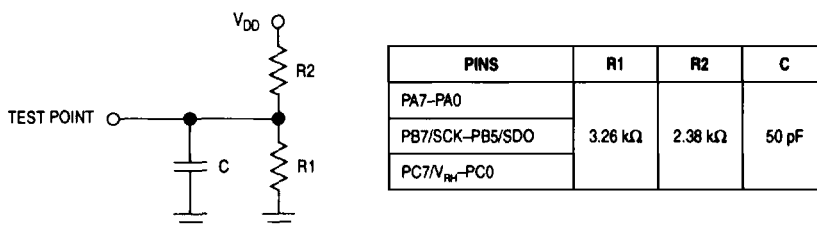
**Table 7. Control Timing ( $V_{DD} = 3.3 \text{ Vdc}$ )<sup>(1)</sup>**

Characteristic	Symbol	Min	Max	Unit
Oscillator Frequency Crystal External Clock	$f_{OSC}$	— dc	2.0 2.0	MHz
Internal Operating Frequency ( $f_{OSC} + 2$ ) Crystal External Clock	$f_{OP}$	— dc	1.0 1.0	MHz
Cycle Time ( $1 + f_{OP}$ )	$t_{CYC}$	1	—	ms
Crystal Oscillator Startup Time	$t_{OXOV}$	—	100	ms
Stop Recovery Startup Time (Crystal Oscillator)	$t_{ILCH}$	—	100	ms
RESET Pulse Width	$t_{RL}$	1.5	—	$t_{CYC}$
Timer Resolution <sup>(2)</sup> Input Capture Pulse Width Input Capture Pulse Period	$t_{RESL}$ $t_H, t_L$ $t_{TTL}$	4.0 250 Note <sup>(3)</sup>	— — —	$t_{CYC}$ ns $t_{CYC}$
Interrupt Pulse Width Low (Edge-Triggered)	$t_{ILIH}$	250	—	ns
Interrupt Pulse Period	$t_{ILIL}$	Note <sup>(4)</sup>	—	$t_{CYC}$
OSC1 Pulse Width	$t_{OH}, t_{OL}$	200	—	ns

1.  $V_{DD} = 3.3 \text{ Vdc} \pm 10\%$ ,  $V_{SS} = 0 \text{ Vdc}$ ,  $T_A = T_L$  to  $T_H$  unless otherwise noted
2. A 2-bit prescaler in the timer is the limiting factor as it counts 4  $t_{CYC}$
3. The minimum  $t_{TTL}$  should not be less than the number of interrupt service routine cycles plus 19  $t_{CYC}$
4. The minimum  $t_{ILIL}$  should not be less than the number of interrupt service routine cycles plus 19  $t_{CYC}$

## Test Load

---



**Figure 5. Test Load**

## Mechanical Specifications

---

The MC68HC705P9 is available in the following packages:

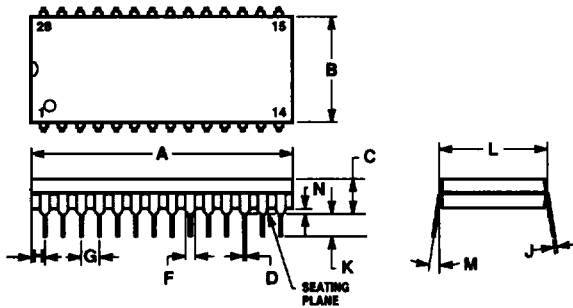
- 710 — Plastic dual in-line package (PDIP)
- 733 — Ceramic dual in-line package (Cerdip)
- 751F — Small outline integrated circuit (SOIC)

The following figures show the latest packages at the time of this publication. To make sure that you have the latest package specifications, contact one of the following:

- Local Motorola Sales Office
- Motorola Mfax
  - Phone 602-244-6609
  - EMAIL [rmfax0@email.sps.mot.com](mailto:rmfax0@email.sps.mot.com)
- Worldwide Web (wwweb) at <http://design-net.com>

Follow Mfax or wwweb on-line instructions to retrieve the current mechanical specifications.

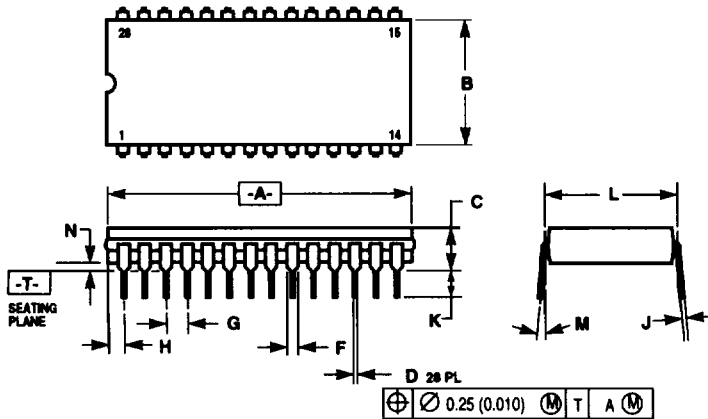
28-Pin PDIP —  
Case #710



- NOTES:
1. POSITIONAL TOLERANCE OF LEADS (D), SHALL BE WITHIN 0.25mm (0.010) AT MAXIMUM MATERIAL CONDITION, IN RELATION TO SEATING PLANE AND EACH OTHER.
  2. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
  3. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	36.45	37.21	1.435	1.465
B	13.72	14.22	0.540	0.560
C	3.94	5.08	0.155	0.200
D	0.38	0.56	0.014	0.022
F	1.02	1.52	0.040	0.060
G	2.54 BSC		0.100 BSC	
H	1.65	2.18	0.065	0.085
J	0.20	0.38	0.008	0.015
K	2.92	3.43	0.115	0.135
L	15.24 BSC		0.600 BSC	
M	0° 18°		0° 18°	
N	0.51	1.02	0.020	0.040

28-Pin Cerdip —  
Case #733

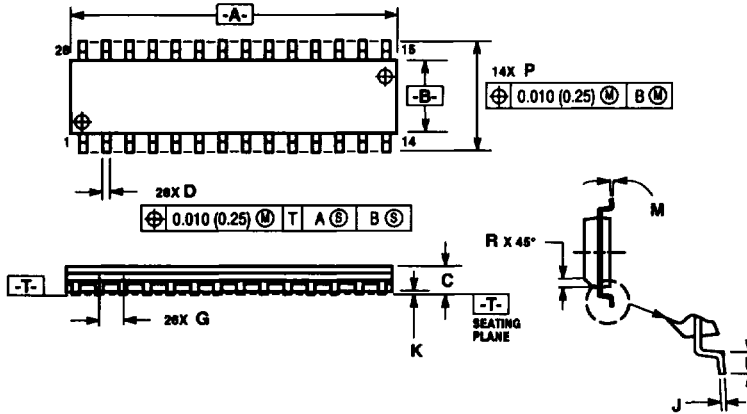


- NOTES:
1. DIMENSIONS A AND B INCLUDES MENISCUS.
  2. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
  3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  4. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.435	1.490	36.45	37.94
B	0.500	0.605	12.70	15.38
C	0.160	0.230	4.06	5.84
D	0.015	0.022	0.38	0.55
F	0.050	0.065	1.27	1.65
G	0.100 BSC		2.54 BSC	
J	0.008	0.012	0.20	0.30
K	0.125	0.160	3.18	4.06
L	0.600 BSC		15.24 BSC	
M	0° 15°		0° 15°	
N	0.020	0.050	0.51	1.27

13-mc88hc705p9

28-Pin SOIC —  
Case #751F



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.006) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	17.80	18.05	0.701	0.711
B	7.40	7.60	0.292	0.299
C	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.41	0.90	0.016	0.035
G	1.27 BSC		0.050 BSC	
J	0.23	0.32	0.009	0.013
K	0.13	0.29	0.005	0.011
M	0°	8°	0°	8°
P	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029